NSN 5962-01-351-5741

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View Online at https://aerobasegroup.com/nsn/5962-01-351-5741

Overall Length:
1.060 inches
Overall Height:
0.400 inches
Body Length:
1.060 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.130 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Satellite communications terminal an/usc-3 (v) 1
Features Provided:
Static operation and hermetically sealed and bidirectional
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
18 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-8 mil-m-38510
Current Rating Per Characteristic:
50.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
55.00 nanoseconds access
Memory Device Type:

Ram

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Fiig: A458a0



Special Features:
Nuclear hardness process
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No